Diode Semiconductor Device - Page 1 of 1



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	rial:
Glass	
Overall Length	:
Between 0.150	inches and 0.170 inches
Overall Diamet	er:
Between 0.068	inches and 0.076 inches
Mounting Meth	nod:
Terminal	
Features Provi	ded:
Hermetically se	aled case
Semiconducto	r Material:
Silicon	
Voltage Rating	In Volts Per Characteristic:
35.0 breakdow	n voltage, dc
Current Rating	Per Characteristic:
10.00 microamp	peres forward current, average peak
Power Rating I	Per Characteristic:
250.0 milliwatts	small-signal input power, common-collector preset
Maximum Ope	rating Tempurature Per Measurement Point:
125.0 degrees of	celsius junction
Special Featur	es:
Voltage rating is	s; junction pattern arrangement: pin
Test Data Doci	ument:
28815-17-1237	87 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes a	any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type	And Quantity:
2 uninsulated w	ire lead
Shelf Life:	
N/a	
Unit Of Measu	re:
Demilitarizatio	n:
No	
Fiig:	